

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group Art Unit:	2814) Attorney Docket: 4425-154
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Examiner:	Long Pham)

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Inventor: Lai Han-Chao LAI ET AL) Art Unit: 2814

Serial No.: 09/888,494) Examiner: L. Pham

Filed: June 26, 2001

For: METHOD FOR FORMING A METAL OXIDE

SEMICONDUCTOR TYPE EFFECT TRANSISTOR

Honorable Commissioner for Patent

And Trademarks

Washington, D.C. 20231

PRELIMINARY AMENDMENT

Sir:

In response to the Final Office Action mailed December 3, 2002, to which a response is due with a three month extension by June 3, 2003, Applicants submit herewith an RCE. Preliminary to examining this application, Applicants respectfully request that the Examiner reconsider the above-identified application according to the following amendment and remarks.

IN THE CLAIMS:

This listing of claims will replace all prior versions, and listings of claims in the application:

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